

**High Performance Differential Fanout Buffer**

**Features**

- 10 differential outputs with 2 banks
- User configurable output signaling standard for each bank: LVDS or LVPECL or HCSL
- LVCMOS reference output up to 200MHz
- Up to 1.5GHz output frequency for differential outputs
- Ultra low additive phase jitter: < 0.02 ps (typ) (differential 156.25MHz, 12KHz to 20MHz integration range); < 0.01 ps (typ) (differential 156.25MHz, 10kHz to 1MHz integration range)
- Selectable reference inputs support either single-ended or differential or Xtal
- Low skew between outputs within banks (<40ps)
- Low delay from input to output (Tpd typ. < 0.9ns)
- Separate Input output supply voltage for level shifting
- 2.5V / 3.3V power supply
- Industrial temperature support
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.  
<https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green available):
  - 48-pin, TQFN (ZD)

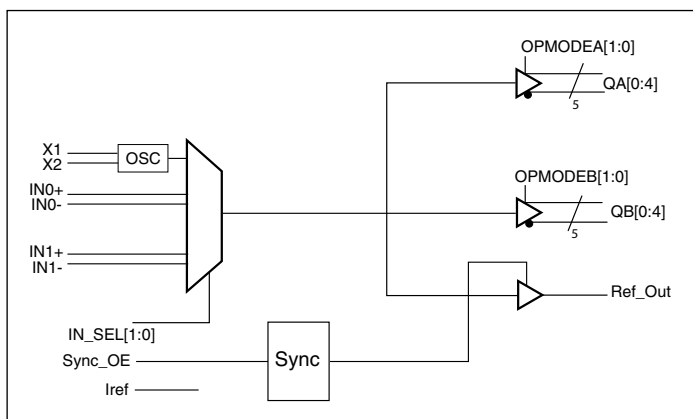
**Description**

The PI6C49S1510A is a high performance fanout buffer device which supports up to 1.5GHz frequency. It also integrates a unique feature with user configurable output signaling standards on per bank basis which provide great flexibilities to users. The device also uses Diodes' proprietary input detection technique to make sure illegal input conditions will be detected and reflected by output states. This device is ideal for systems that need to distribute low jitter clock signals to multiple destinations.

**Applications**

- Networking systems including switches and Routers
- High frequency backplane based computing and telecom platforms

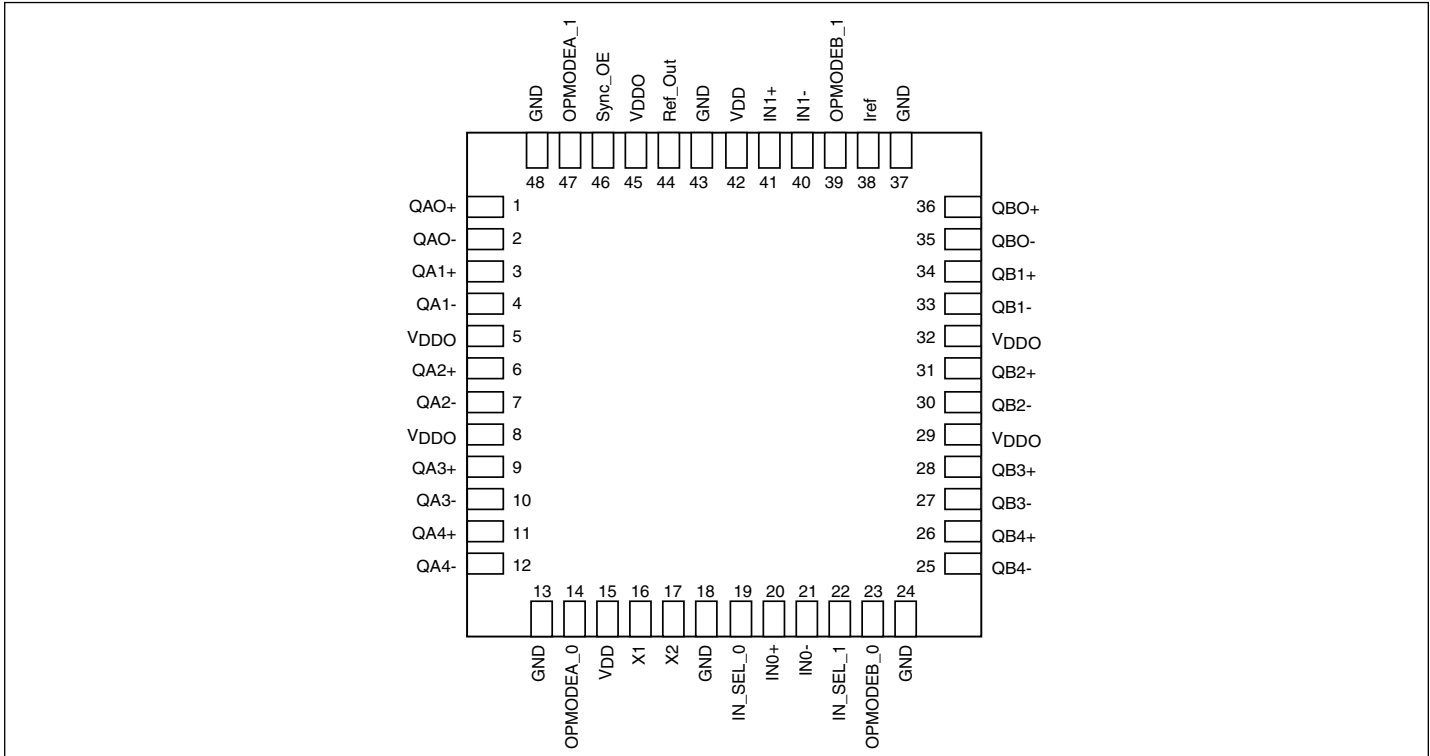
**Block Diagram**



**Notes:**

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Configuration



## Pin Description

| Pin #                     | Pin Name     | Type   | Description  |   |
|---------------------------|--------------|--------|--|---|
| 1,<br>2                   | QA0+<br>QA0- | Output | Bank A differential output pair 0. Pin selectable LVPECL/LVDS/HCSL interface levels. |   |
| 3,<br>4                   | QA1+<br>QA1- | Output | Bank A differential output pair 1. Pin selectable LVPECL/LVDS/HCSL interface levels. |   |
| 5, 8, 29, 32, 45          | VDDO         | Power  | Power supply pins for IO   |   |
| 6,<br>7                   | QA2+<br>QA2- | Output | Bank A differential output pair 2. Pin selectable LVPECL/LVDS/HCSL interface levels. |   |
| 9,<br>10                  | QA3+<br>QA3- | Output | Bank A differential output pair 3. Pin selectable LVPECL/LVDS/HCSL interface levels. |   |
| 11,<br>12                 | QA4+<br>QA4- | Output | Bank A differential output pair 4. Pin selectable LVPECL/LVDS/HCSL interface levels. |   |
| 13, 18, 24, 37,<br>43, 48 | GND          | Power  | Power supply ground  |   |
| 14, 47                    | OPMODEA      | Input  | Pull-down  | Output mode select for Bank A. See Table 2 for functions, LVCMOS/LVTTL interface levels |
| 15, 42                    | VDD          | Power  | Power supply pins  |   |

**Pinout Description Cont.**

| Pin #     | Pin Name     | Type   |                       | Description   |
|-----------|--------------|--------|-----------------------|---|
| 16        | X1           | Input  |                       | XTAL input, can also be used as single ended input pin  |
| 17        | X2           | Output |                       | XTAL output. If X1 is used as a single ended input pin, X2 is to be left open   |
| 19, 22    | IN_SEL       | Input  | Pull-down             | Input clock select. See Table 1 for function. LVCMOS/LVTTL interface levels.  |
| 20        | IN0+         | Input  | Pull-down             | Reference input 0   |
| 21        | IN0-         | Input  | Pull-up/<br>Pull-down | Inverted reference input 0, internal bias to $V_{DD}/2$   |
| 23, 39    | OPMODEB      | Input  | Pull-down             | Output mode select for Bank B. See Table 2 for functions, LVCMOS/LVTTL interface levels   |
| 26,<br>25 | QB4+<br>QB4- | Output |                       | Bank B differential output pair 4. Pin selectable LVPECL/LVDS/HCSL interface levels.  |
| 28,<br>27 | QB3+<br>QB3- | Output |                       | Bank B differential output pair 3. Pin selectable LVPECL/LVDS/HCSL interface levels.  |
| 31,<br>30 | QB2+<br>QB2- | Output |                       | Bank B differential output pair 2. Pin selectable LVPECL/LVDS/HCSL interface levels.  |
| 34,<br>33 | QB1+<br>QB1- | Output |                       | Bank B differential output pair 1. Pin selectable LVPECL/LVDS/HCSL interface levels.  |
| 36,<br>35 | QB0+<br>QB0- | Output |                       | Bank B differential output pair 0. Pin selectable LVPECL/LVDS/HCSL interface levels.  |
| 38        | Iref         | Output |                       | A fixed precision resistor (475ohm) from this pin to ground provides a reference current for HCSL mode. If LVPECL or LVDS mode chosen, pin can be left open |
| 40        | IN1-         | Input  | Pull-up/<br>Pull-down | Inverted reference input, internal bias to $V_{DD}/2$   |
| 41        | IN1+         | Input  | Pull-down             | Reference input 1   |
| 44        | Ref_Out      | Output |                       | Reference output, CMOS  |
| 46        | Sync_OE      | Input  | Pull-down             | Synchronous output enable for Ref_Out, see Table 3 for functions  |

## Function Table

**Table 1: Input Select Function**

| IN_SEL [1] | IN_SEL [0] | Function                            |
|------------|------------|-------------------------------------|
| 0          | 0          | IN0 is the selected reference input |
| 0          | 1          | IN1 is the selected reference input |
| 1          | X          | XTAL is the selected input          |

**Table 2: Output Mode Select Function**

| OPMODEA/B [1] | OPMODEA/B [0] | Output Bank A / Bank B Mode |
|---------------|---------------|-----------------------------|
| 0             | 0             | LVPECL                      |
| 0             | 1             | LVDS                        |
| 1             | 0             | HCSL                        |
| 1             | 1             | Hi-Z                        |

**Table 3: Reference Output Enable Function**

| Sync_OE | Ref_Out        |
|---------|----------------|
| 0       | Hi-Z           |
| 1       | Output enabled |

**Table 4: Illegal Input Level Function**

| Input illegal status | Output status |
|----------------------|---------------|
| Input open           | Logic Low     |
| Input both high      | Logic Low     |
| Input both low       | Logic Low     |

## Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested)

|   |                       |
|---|-----------------------|
| Storage temperature.....                                    | -55 to +150°C         |
| Supply Voltage to Ground Potential ( $V_{DD}, V_{DDO}$ )... | -0.5 to +4.6V         |
| Inputs (Referenced to GND) .....                            | -0.5 to $V_{DD}+0.5V$ |
| Clock Output (Referenced to GND).....                       | -0.5 to $V_{DD}+0.5V$ |
| Latch up .....  | 200mA                 |
| ESD Protection (Input) .....                                | 2000V min (HBM)       |
| Junction Temperature .....                                  | 125 °C max            |

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## Power Supply Characteristics and Operating Conditions

| Symbol    | Parameter                                    | Test Condition              | Min.  | Typ. | Max.  | Units |
|-----------|--|-----------------------------|-------|------|-------|-------|
| $V_{DD}$  | Core Supply Voltage                          |                             | 2.375 |      | 3.465 | V     |
| $V_{DDO}$ | Output Supply Voltage                        |                             | 2.375 |      | 3.465 | V     |
| $I_{DD}$  | Core Power Supply Current                    |                             |       | 90   | 130   | mA    |
| $I_{DDO}$ | Output Power Supply Current                  | All LVPECL outputs unloaded |       | 150  | 190   |       |
|           |  | All LVDS outputs loaded     |       | 110  | 140   |       |
|           |  | All HCSL outputs unloaded   |       | 80   | 120   |       |
| $T_A$     | Ambient Operating Temperature <sup>(1)</sup> |                             | -40   |      | 85    | °C    |
| $T_B$     | PCB Operating Temperature <sup>(1)</sup>     |                             | -40   |      | 105   | °C    |

Note 1: Either  $T_A$  or  $T_B$  used as operating condition

## DC Electrical Specifications - Differential Inputs

| Symbol      | Parameter                          | Test Condition   | Min. | Typ. | Max.          | Units |
|-------------|------------------------------------|------------------|------|------|---------------|-------|
| $I_{IH}$    | Input High current                 | Input = $V_{DD}$ |      |      | 150           | uA    |
| $I_{IL}$    | Input Low current                  | Input = GND      | -150 |      |               | uA    |
| $C_{IN}$    | Input capacitance                  |                  |      | 3    |               | PF    |
| $V_{IH}$    | Input high voltage                 |                  |      |      | $V_{DD}+0.3$  | V     |
| $V_{IL}$    | Input low voltage                  |                  | -0.3 |      |               | V     |
| $V_{ID}$    | Input Differential Amplitude PK-PK |                  | 0.15 |      | $V_{DD}-0.85$ | V     |
| $V_{CM}$    | Common mode input voltage          |                  | 0.25 |      | $V_{DD}-1.2$  | V     |
| $ISO_{MUX}$ | MUX isolation                      |                  |      | -89  |               | dBc   |

### DC Electrical Specifications - LVCMOS Inputs

| Symbol   | Parameter          | Conditions       | Min. | Typ. | Max.         | Units   |
|----------|--------------------|------------------|------|------|--------------|---------|
| $I_{IH}$ | Input High current | Input = $V_{DD}$ |      |      | 150          | $\mu A$ |
| $I_{IL}$ | Input Low current  | Input = GND      | -150 |      |              | $\mu A$ |
| $V_{IH}$ | Input high voltage | $V_{DD}=3.3V$    | 2.0  |      | $V_{DD}+0.3$ | V       |
| $V_{IL}$ | Input low voltage  | $V_{DD}=3.3V$    | -0.3 |      | 0.8          | V       |
| $V_{IH}$ | Input high voltage | $V_{DD}=2.5V$    | 1.7  |      | $V_{DD}+0.3$ | V       |
| $V_{IL}$ | Input low voltage  | $V_{DD}=2.5V$    | -0.3 |      | 0.7          | V       |

### DC Electrical Specifications- LVPECL Outputs

| Parameter | Description         | Conditions | Min.          | Typ. | Max.          | Units |
|-----------|---------------------|------------|---------------|------|---------------|-------|
| $V_{OH}$  | Output High voltage |            | $V_{DDO}-1.4$ |      | $V_{DDO}-0.9$ | V     |
| $V_{OL}$  | Output Low voltage  |            | $V_{DDO}-2.2$ |      | $V_{DDO}-1.7$ | V     |

### DC Electrical Specifications- LVDS Outputs

| Parameter  | Description  | Conditions | Min. | Typ. | Max. | Units    |
|------------|--|------------|------|------|------|----------|
| $V_{OH}$   | Output High voltage                                  |            |      | 1.43 |      | V        |
| $V_{OL}$   | Output Low voltage                                   |            |      | 1.0  |      | V        |
| $V_{ocm}$  | Output commode voltage                               |            |      | 1.25 |      | V        |
| $DV_{ocm}$ | Change in $V_{ocm}$ between completely output states |            |      |      | 50   | mV       |
| $R_o$      | Output impedance                                     |            | 85   |      | 140  | $\Omega$ |

### DC Electrical Specifications - HCSL Outputs

| Parameter | Description         | Conditions | Min. | Typ. | Max. | Units |
|-----------|---------------------|------------|------|------|------|-------|
| $V_{OH}$  | Output High voltage |            | 520  |      | 900  | mV    |
| $V_{OL}$  | Output Low voltage  |            | -150 |      | 150  | mV    |

**DC Electrical Specifications – LVCMOS Output**

| Parameter        | Description         | Conditions   | Min. | Typ. | Max. | Units |
|------------------|---------------------|--|------|------|------|-------|
| V <sub>OH</sub>  | Output High voltage | V <sub>DDO</sub> =3.3V +/-5%, I <sub>OH</sub> = 8mA    | 2.3  |      |      | V     |
|                  |                     | V <sub>DDO</sub> =2.5V +/- 5%, I <sub>OH</sub> = 8mA   | 1.5  |      |      | V     |
| V <sub>OL</sub>  | Output Low voltage  | V <sub>DDO</sub> =3.3V +/-5%, I <sub>OL</sub> = -8mA   |      |      | 0.5  | V     |
|                  |                     | V <sub>DDO</sub> =2.5V +/- 5%, I <sub>OL</sub> = -8mA  |      |      | 0.4  | V     |
| V <sub>OH</sub>  | Output High voltage | V <sub>DDO</sub> =3.3V +/-5%, I <sub>OH</sub> = 24mA   | 2.1  |      |      | V     |
|                  |                     | V <sub>DDO</sub> =2.5V +/- 5%, I <sub>OH</sub> = 16mA  | 1.5  |      |      | V     |
| V <sub>OL</sub>  | Output Low voltage  | V <sub>DDO</sub> =3.3V +/-5%, I <sub>OL</sub> = -24mA  |      |      | 1    | V     |
|                  |                     | V <sub>DDO</sub> =2.5V +/- 5%, I <sub>OL</sub> = -16mA |      |      | 0.8  | V     |
| R <sub>IUT</sub> | Output Impedance    | V <sub>DDO</sub> = 3.3V ± 5%                           |      | 17   |      | Ω     |
|                  |                     | V <sub>DDO</sub> = 2.5V ± 5%                           |      | 22   |      | Ω     |

**AC Electrical Specifications – Differential Outputs**

| Parameter                                    | Description               | Conditions                                   | Min.                         | Typ. | Max. | Units |    |
|--|---------------------------|--|------------------------------|------|------|-------|----|
| F <sub>OUT</sub>                             | Clock output frequency    | LVPECL, LVDS                                 |                              |      | 1500 | MHz   |    |
|  |                           | HCSL   |                              |      | 250  |       |    |
| T <sub>r</sub>                               | Output rise time          | From 20% to 80%                              | LVPECL                       | 120  | 150  | 300   | ps |
|  |                           |  | LVDS                         | 120  | 150  | 300   |    |
|  |                           |  | HCSL                         | 300  |      | 700   |    |
| T <sub>f</sub>                               | Output fall time          | From 80% to 20%                              | LVPECL                       | 120  | 150  | 300   | ps |
|  |                           |  | LVDS                         | 120  | 150  | 300   |    |
|  |                           |  | HCSL                         | 300  |      | 700   |    |
| T <sub>ODC</sub>                             | Output duty cycle         | Frequency<650MHz,<br>V <sub>ID</sub> ≥ 400mV | LVPECL,<br>HCSL<br>(<250MHz) | 48   |      | 52    | %  |
|  |                           |  | LVDS                         | 47   |      | 53    |    |
|  |                           | Frequency<1GHz,<br>V <sub>ID</sub> ≥ 400mV   | LVPECL                       | 45   |      | 55    |    |
|  |                           |  | LVDS                         | 45   |      | 55    |    |
|  |                           | Frequency<1.5GHz,<br>V <sub>ID</sub> ≥ 400mV | LVDS                         | 40   |      | 60    |    |
| Frequency<1.5GHz, V <sub>ID</sub><br>≥ 400mV | LVPECL                    | 40   |                              | 60   |      |       |    |
| V <sub>PP</sub>                              | Output swing Single-ended | LVPECL outputs @ <1GHz                       | 500                          |      | 1100 | mV    |    |
|  |                           | LVPECL outputs @ >1GHz                       | 400                          |      | 1000 |       |    |
|  |                           | LVDS outputs @ <1GHz                         | 250                          |      | 600  |       |    |
|  |                           | LVDS outputs @ >1GHz                         | 250                          |      | 550  |       |    |

**AC Electrical Specifications – Differential Outputs Cont.**

| Parameter             | Description                         | Conditions  | Min. | Typ. | Max. | Units |
|-----------------------|-------------------------------------|---|------|------|------|-------|
| T <sub>j</sub>        | Buffer additive jitter RMS          | 156.25MHz, 12kHz to 20MHz   |      | 0.02 |      | ps    |
|                       |                                     | 156.25MHz, 10kHz to 1MHz  |      | 0.01 |      | ps    |
| V <sub>CROSS</sub>    | Absolute crossing voltage           | HCSL  |      | 460  |      | mV    |
| DV <sub>CROSS</sub>   | Total variation of crossing voltage | HCSL  |      |      | 140  | mV    |
| T <sub>SK</sub>       | Output Skew                         | 10 outputs devices, outputs in same tank, with same load, at DUT. |      | 15   | 40   | ps    |
| T <sub>PD</sub>       | Propagation Delay                   | LVPECL, LVDS @ 3.3V, 100MHz                                       |      | 570  |      | ps    |
|                       |                                     | HCSL @ 3.3V, 100MHz   |      | 900  |      | ps    |
| T <sub>OD</sub>       | Valid to HiZ                        |   |      |      | 80   | ns    |
| T <sub>OE</sub>       | HiZ to valid                        |   |      |      | 80   | ns    |
| T <sub>P2P Skew</sub> | Part to Part Skew <sup>(1)</sup>    |   |      | 80   | 120  | ps    |

**AC Electrical Specifications – CMOS**

| Parameter                      | Description                  | Conditions            | Min. | Typ. | Max. | Units  |
|--------------------------------|------------------------------|-----------------------|------|------|------|--------|
| F <sub>OUT</sub>               | Ref_Out frequency            | XTAL input            | 10   |      | 50   | MHz    |
|                                |                              | Reference input       |      |      | 200  | MHz    |
| T <sub>j</sub>                 | Buffer additive jitter RMS   | XTAL input            |      | 0.3  |      | ps     |
|                                |                              | Reference input       |      | 0.03 |      | ps     |
| t <sub>r</sub> /t <sub>f</sub> | Rise time, Fall time         | C <sub>L</sub> = 10pF |      | 1.5  |      | ns     |
| T <sub>ODC</sub>               | Output duty cycle            | C <sub>L</sub> = 10pF | 45   |      | 55   | %      |
| t <sub>PD</sub>                | Propagation delay            | 3.3V, 25MHz           |      | 2200 |      | ps     |
| t <sub>S</sub>                 | Setup time                   |                       | 300  |      |      | ps     |
| t <sub>SOD</sub>               | Clock edge to output disable | Ref_Out               | 2    |      | 4    | cycles |
| t <sub>SOE</sub>               | Clock edge to output enable  | Ref_Out               | 2    |      | 4    | cycles |

**Notes:**

1. This parameter is guaranteed by design

**Crystal Characteristics**

| Parameter                          | Min.        | Typ. | Max. | Units |
|------------------------------------|-------------|------|------|-------|
| Mode of Oscillation                | Fundamental |      |      |       |
| Frequency Range                    | 10          |      | 50   | MHz   |
| Equivalent Series Resistance (ESR) |             |      | 70   | Ω     |
| Shunt Capacitance                  |             |      | 7    | pF    |
| Load Capacitance                   | 10          |      | 18   | pF    |
| Drive Level                        |             |      | 500  | μW    |

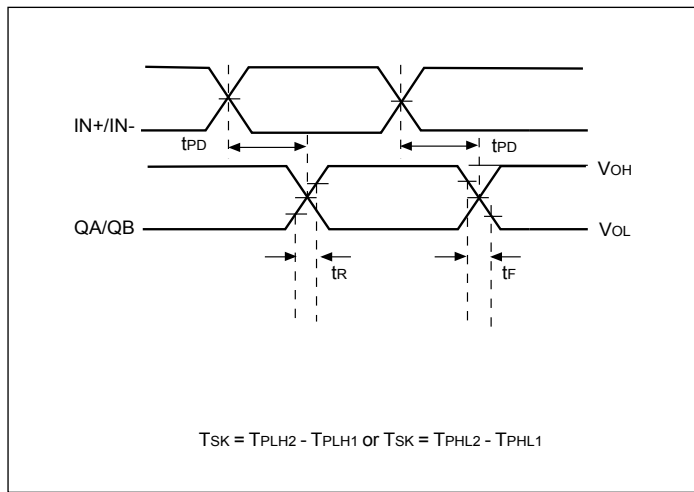


## Recommended Crystals

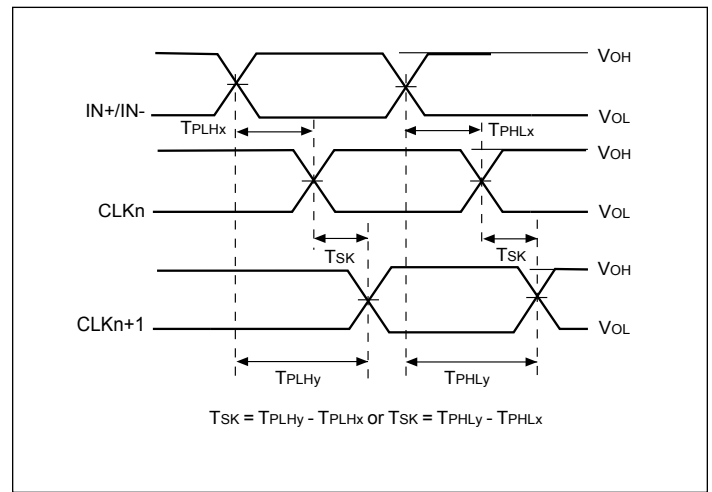
Diodes recommends:

- a) GC2500003 XTAL 49S/SMD(4.0 mm), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/GC\\_GF.pdf](http://www.pericom.com/pdf/datasheets/se/GC_GF.pdf)
- b) FY2500091, SMD 5x3.2(4P), 25M, CL=18pF, +/-30ppm  
[http://www.pericom.com/pdf/datasheets/se/FY\\_F9.pdf](http://www.pericom.com/pdf/datasheets/se/FY_F9.pdf)
- c) FL2500047, SMD 3.2x2.5(4P), 25M, CL=18pF, +/-20ppm  
<http://www.pericom.com/pdf/datasheets/se/FL.pdf>

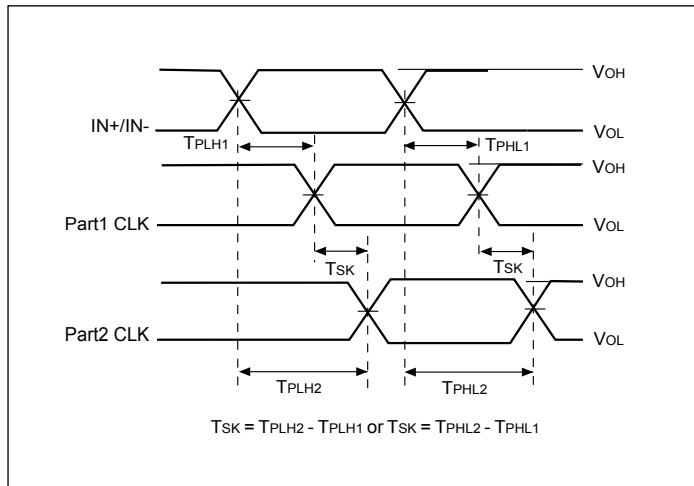
## Propagation Delay



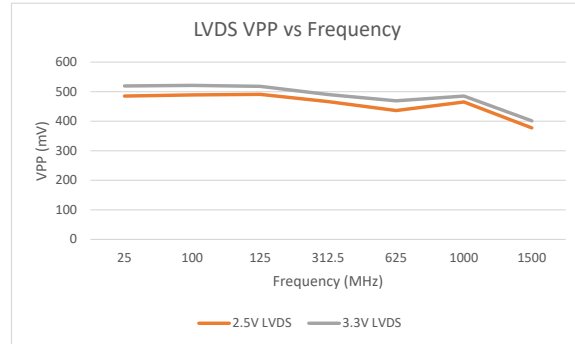
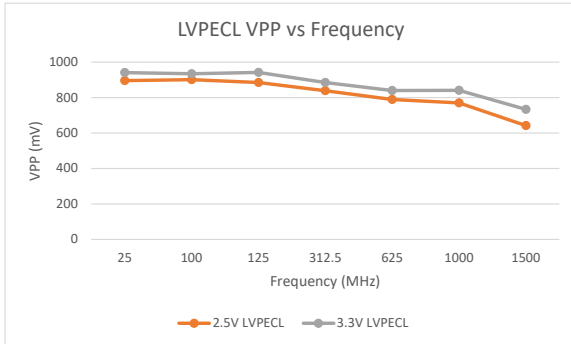
## Output Skew



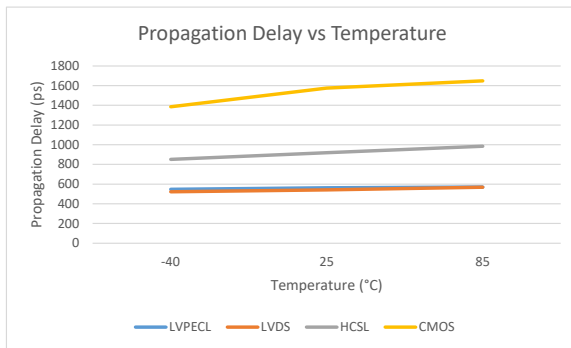
## Part to Part Skew



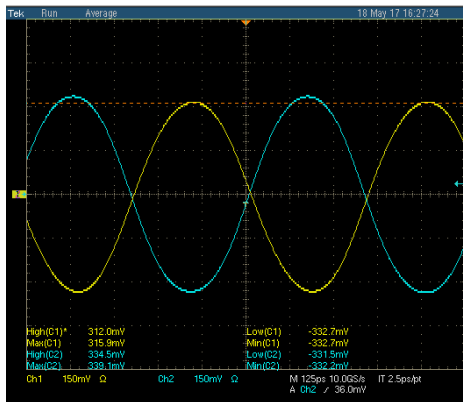
**LVPECL/ LVDS Output Swing vs. Frequency**



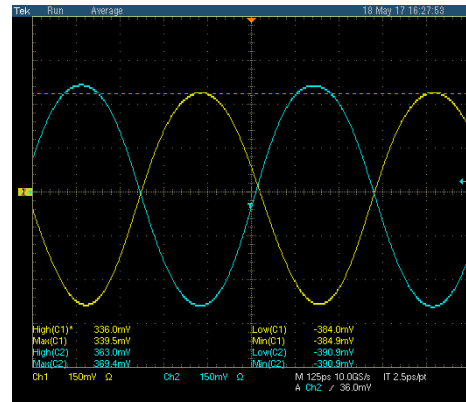
**Propagation Delay vs Temperature**



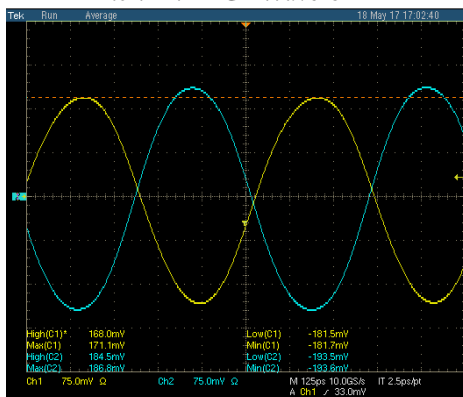
**1.5GHz LVPECL/ LVDS Waveform**



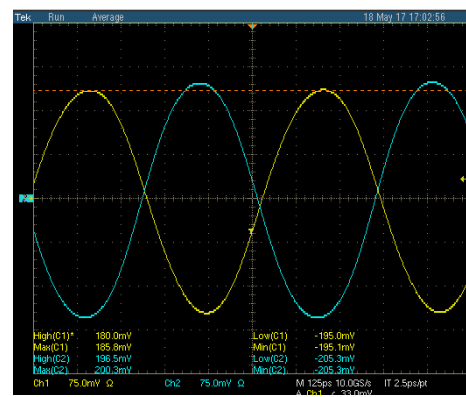
**2.5V LVPECL Waveform**



**3.3V LVPECL Waveform**



**2.5V LVDS Waveform**

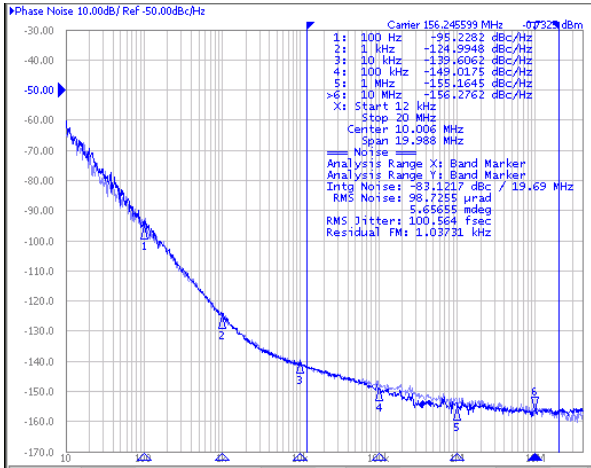


**3.3V LVDS Waveform**

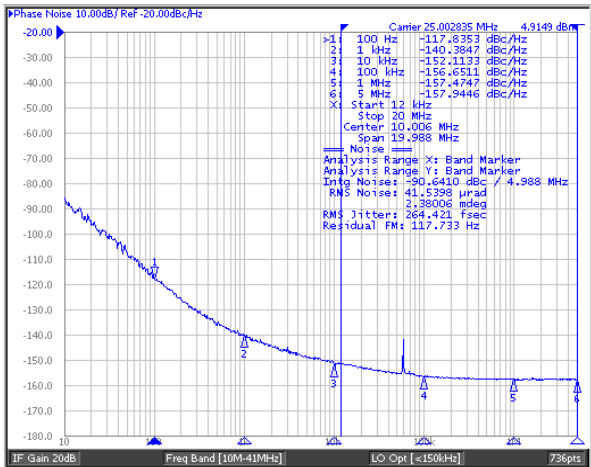
## Phase Noise and Additive Jitter

Output phase noise (Dark Blue) vs Input Phase noise (light blue)

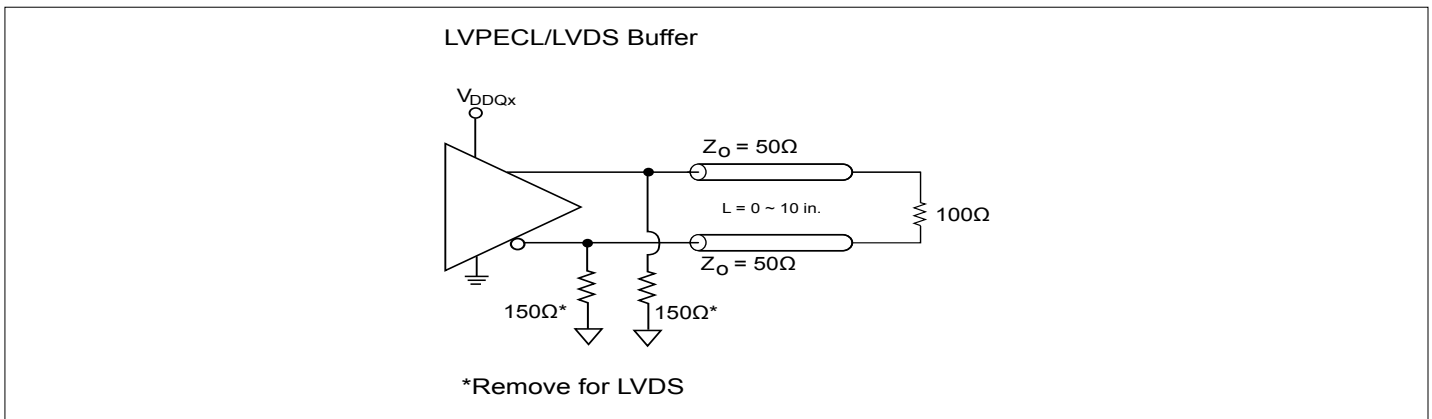
Additive jitter is calculated at 156.25MHz~27fs RMS (12kHz to 20MHz). Additive jitter =  $\sqrt{(\text{Output jitter}^2 - \text{Input jitter}^2)}$



Total phase jitter with 25MHz XTAL ~ 264fs RMS (12kHz ~20MHz)

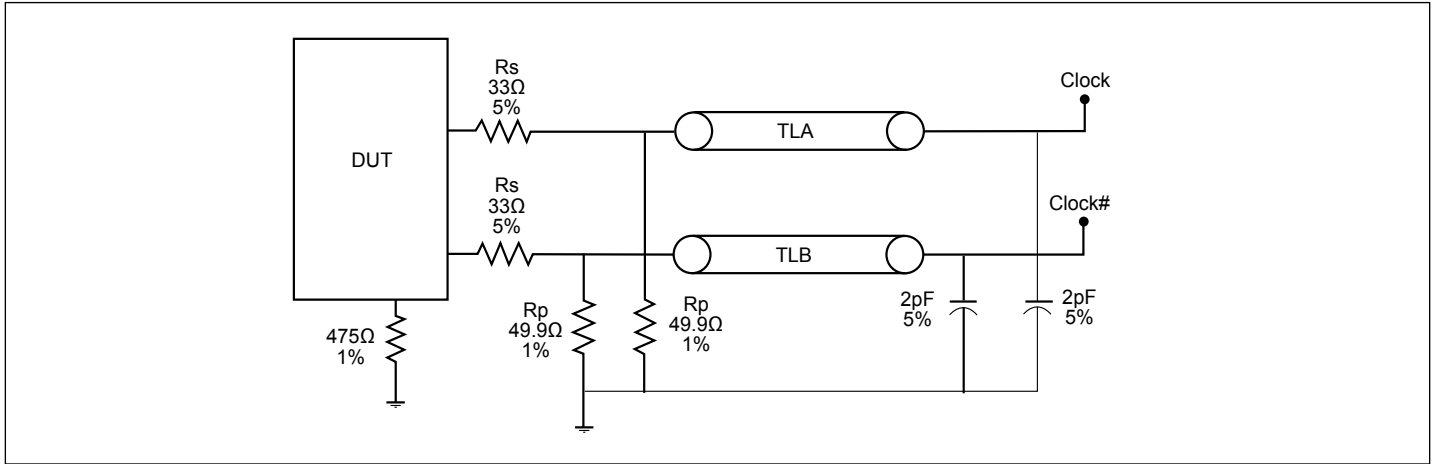


## Configuration Test Load Board Termination for LVPECL/ LVDS Outputs

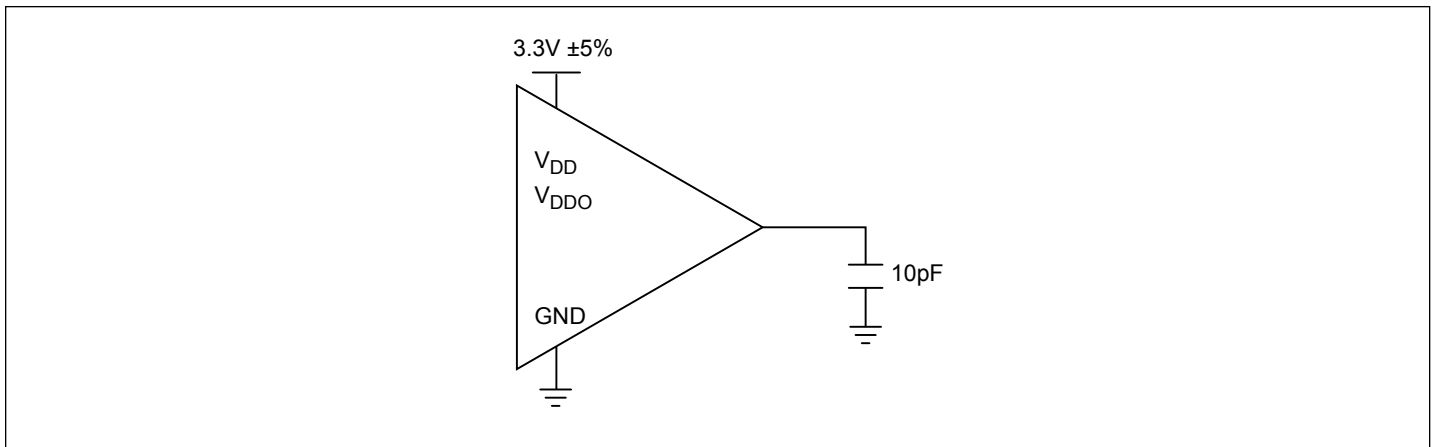


**PI6C49S1510A**

**Configuration Test Load Board Termination for HCSL Outputs**



**Configuration Test Load Board Termination for LVCMOS Outputs**



## Application Information

### Wiring the differential input to accept single ended levels

Figure 1 shows how the differential input can be wired to accept single ended levels. The reference voltage  $V_{REF} = V_{DD}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the  $V_{REF}$  in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{DD} = 3.3V$ ,  $V_{REF}$  should be 1.25V and  $R1/R2 = 0.609$ .

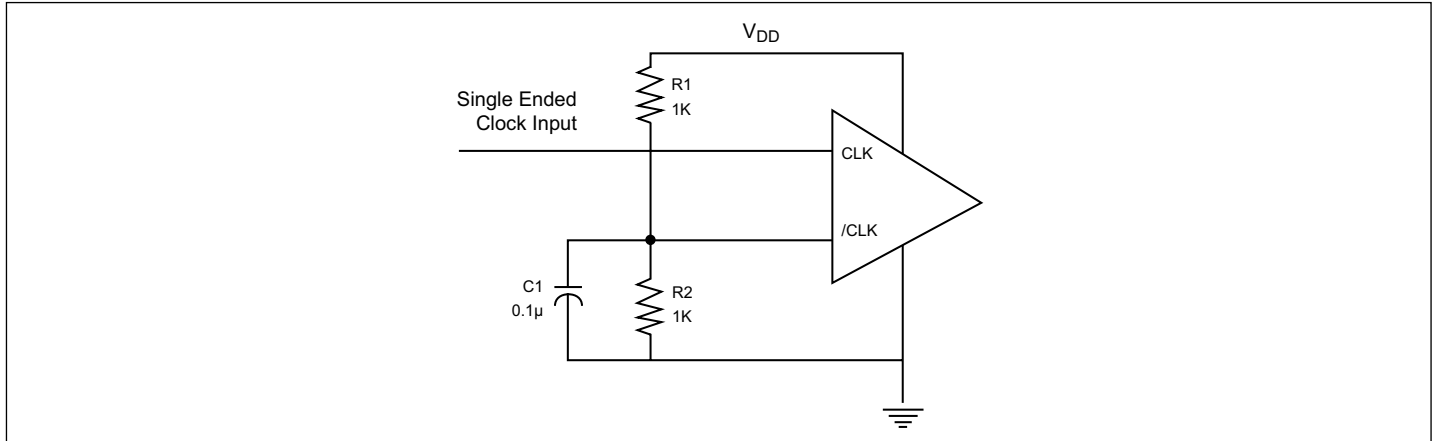
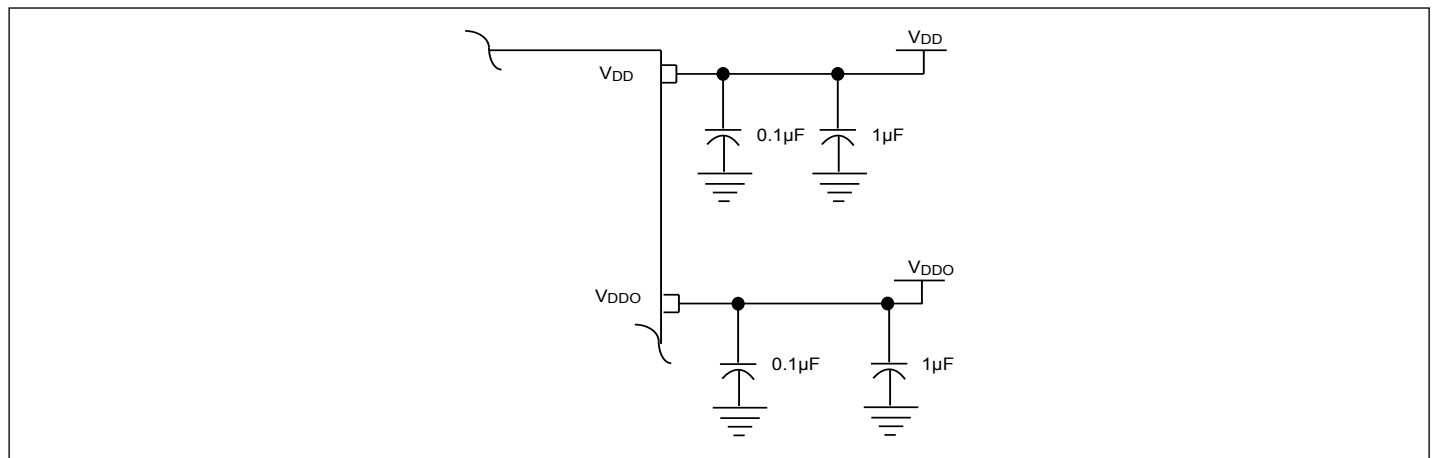


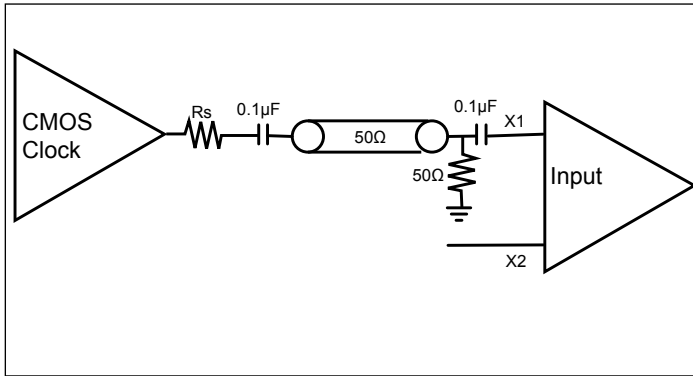
Figure 1. Single-ended input to Differential input device

### Power Supply Filtering Techniques

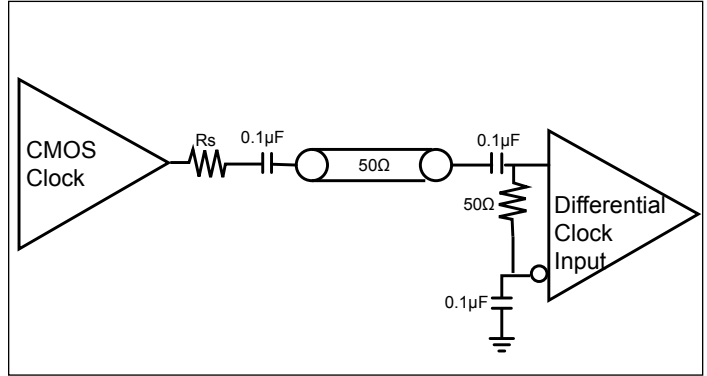
As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. All power pins should be individually connected to the power supply plane through vias, and 0.1µF and 1µF bypass capacitors should be used for each pin.



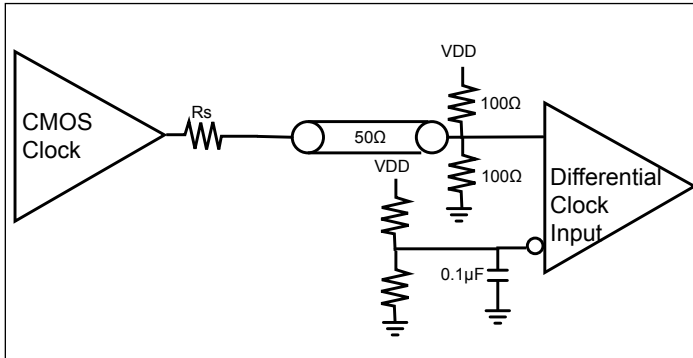
**Driving X1 with a Single Ended Input**



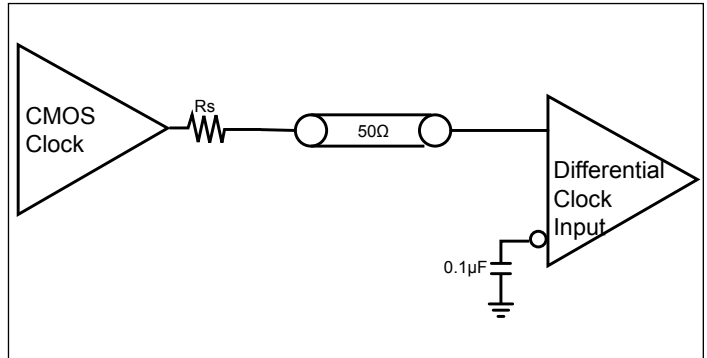
**Single Ended Input, AC Couple**



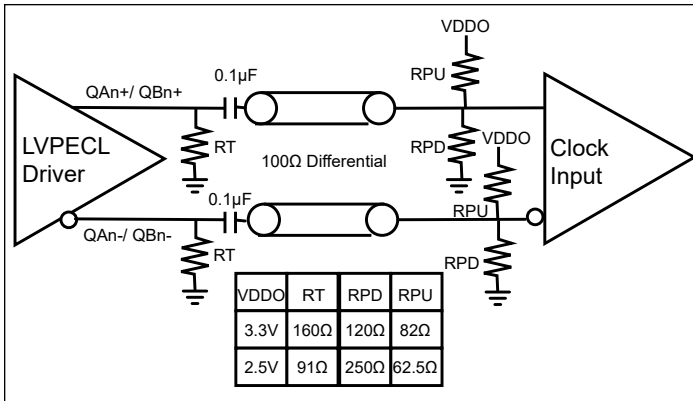
**Single Ended Input, DC Couple**



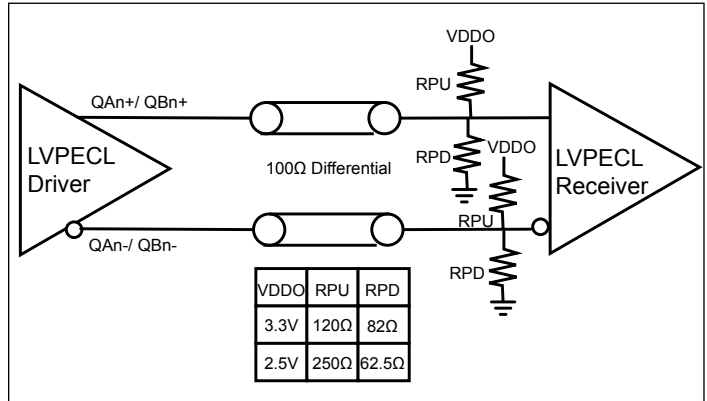
**Single Ended Input, DC Couple**



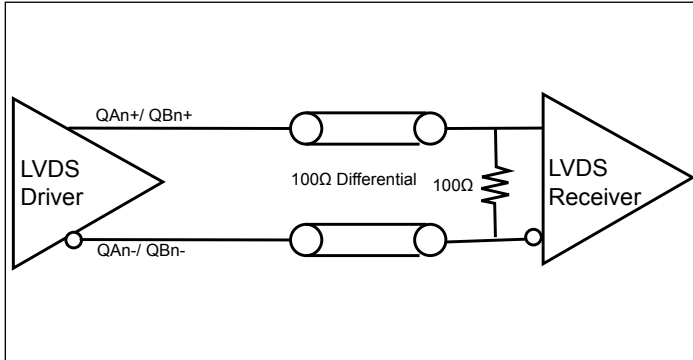
**LVPECL, AC Couple, Thevenin Equivalent**



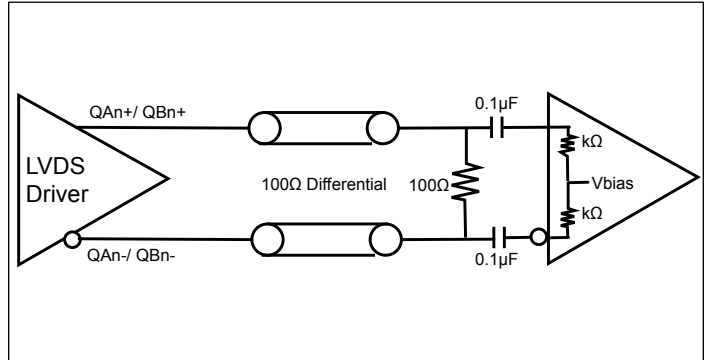
**LVPECL, DC Couple, Thevenin Equivalent**



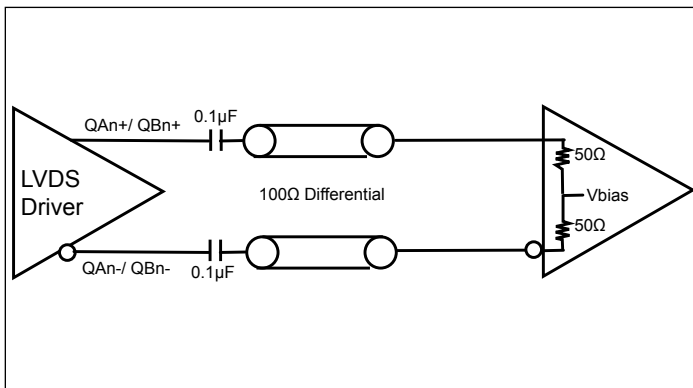
**LVDS DC Couple**



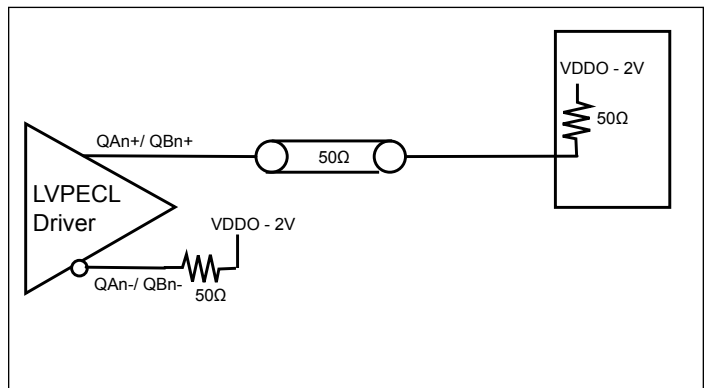
**LVDS AC Couple at Load**



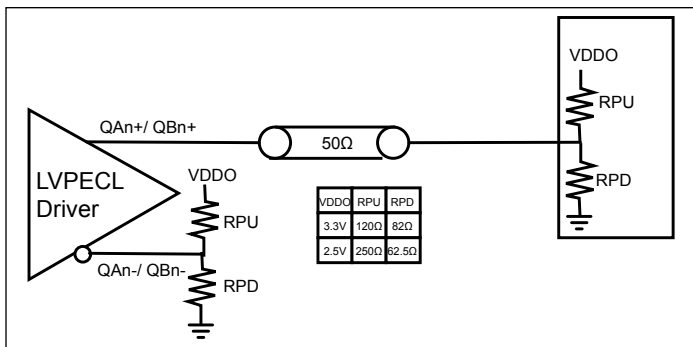
**LVDS AC Couple with Internal Termination**



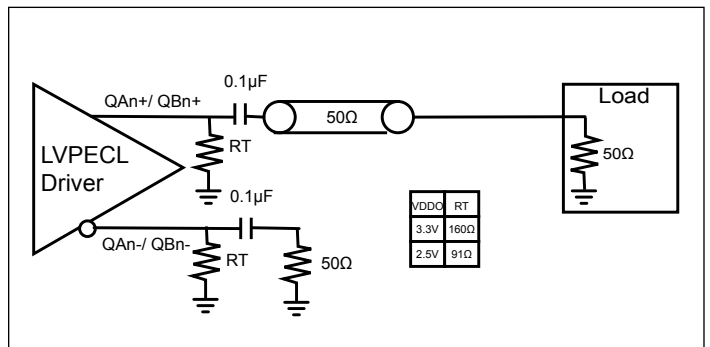
**Single Ended LVPECL, DC Couple**



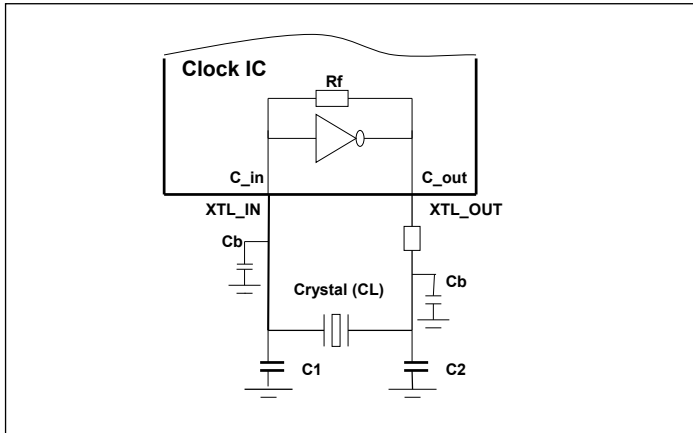
**Single Ended LVPECL, DC Couple, Thevenin Equivalent**



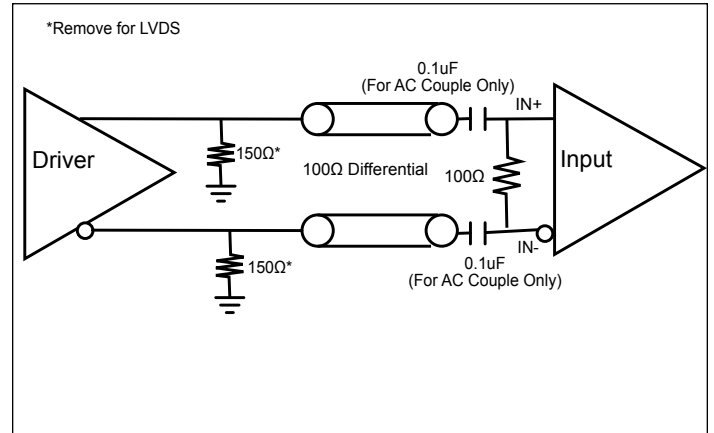
**Single Ended LVPECL, AC Couple, Thevenin Equivalent**



**Clock IC Crystal Input Guide**

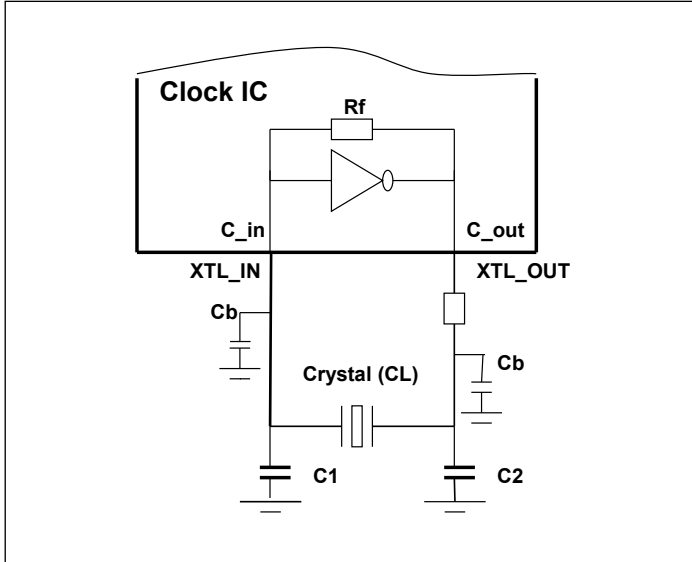


**LVPECL/ LVDS AC and DC Input**





## Clock IC Crystal loading cap. Design Guide



CL =crystal spec. loading cap.

C\_in/out = (3~5pF) of IC pin cap.

Cb = PCB trace (2~4pF)

C1,C2 = load cap. of design

Rd = 50 to 100Ω drive level limit

Design guide:  $C1=C2=2 *CL - (Cb +C_{in/out})$  to meet target +/-ppm < 20 ppm

Example 1: Select CL=18 pF crystal,  $C1=C2=2*(18pF) - (4pF+5pF)=27pF$ , check datasheet too

Example 2: For higher frequency crystal ( $\Rightarrow 20MHz$ ), can use formula  $C1=C2=2*(CL-6)$ , can do fine tune of C1, C2 for more accurate ppm if necessary

## Thermal Information

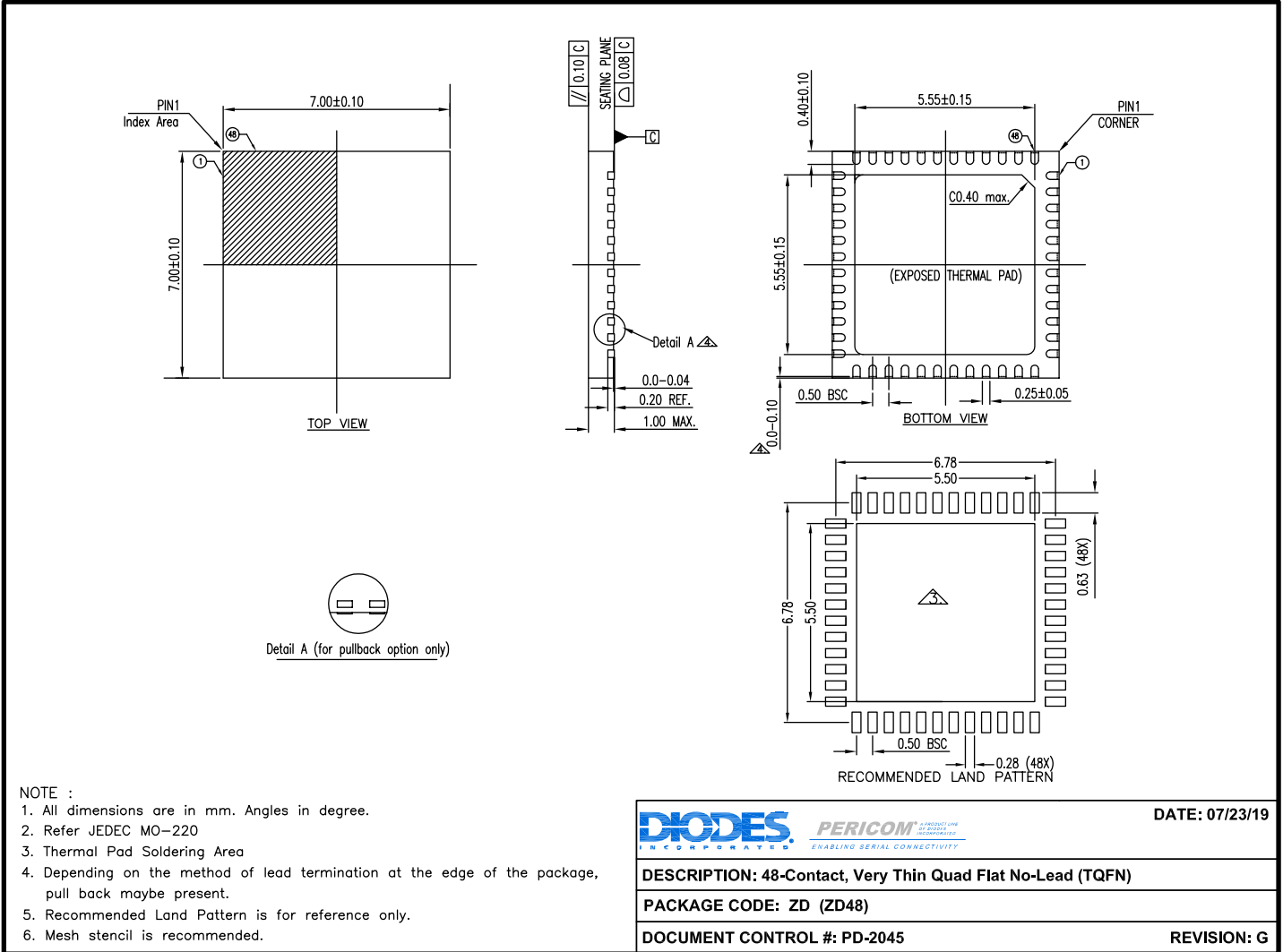
| Symbol        | Description                            | Condition |            |
|---------------|--|-----------|------------|
| $\theta_{JA}$ | Junction-to-ambient thermal resistance | Still air | 23.65 °C/W |
| $\theta_{JC}$ | Junction-to-case thermal resistance    |           | 9.10 °C/W  |

## Part Marking

|  |  |
|--|--|
|  | <p>YY : Year<br/>                 WW : Workweek<br/>                 1st X : Assembly Site Code<br/>                 2nd X : Wafer Site Code</p> |
|--|--|

**Packaging Mechanical**

**48-TQFN (ZD)**



19-1087

For latest package info.

please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

**Ordering Information**

| Ordering Code      | Package Code | Package Description                            | Operating Temperature |
|--------------------|--------------|--|-----------------------|
| PI6C49S1510AZDIEEX | ZD           | 48-Contact, Very Thin Quad Flat No-Lead (TQFN) | -40 °C to 85 °C       |

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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